

APPLICATION DATA SHEET

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Attorney Docket Number: XDEV1100

Application Type: utility

Title of Invention: CONTACT METHOD FOR THIN SILICON CARBIDE EPITAXIAL LAYER
AND SEMICONDUCTOR DEVICES FORMED BY THOSE METHODS

[Request Not To Publish:]

Attorney Docket Number: XDEV1100

Customer Number Attorney: 25094



Customer Number Correspondence Address: 25094



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